L Number	Hits	Search Text	DB	Time stamp
1	159	power near5 dissipation same ((semiconductor$1) or (transistor$1)) same (junction near5 temperature)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/31 11:24
2	5	(power near5 dissipation same ((semiconductor$1) or (transistor$1)) same (junction near5 temperature)) and instantaneous adj2 power with dissipat$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/31 11:33
6	23	(power near5 dissipation same ((semiconductor$1) or (transistor$1)) same (junction near5 temperature)) and sampl$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/31 11:33